



15A, 35V - 150V Schottky Barrier Rectifier

FEATURES

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

• Case: TO-220AB

• Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

Mounting torque: 0.56 N·m maximum
Meet JESD 201 class 2 whisker test

• Polarity: As marked

• Weight: 1.88g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
I _F	15	Α				
V_{RRM}	35 - 150	V				
I _{FSM}	150	Α				
T_{JMAX}	150	°C				
Package	TO-220AB					
Configuration	Dual dies					

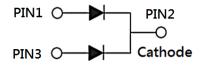








TO-220AB



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
		MBR	MBR	MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	1535	1545	1550	1560	1590	15100	15150	UNIT
		CT	CT	СТ	СТ	CT	CT	CT	
Marking code on the		MBR	MBR	MBR	MBR	MBR	MBR	MBR	
device		1535	1545	1550	1560	1590	15100	15150	
		CT	CT	CT	CT	CT	CT	CT	
Repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	$V_{R(RMS)}$	24	31	35	42	63	70	105	V
Forward current	I _F				15				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}				150				А
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}	1 0.5			Α				
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	15						Α	

1



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MBR 1535 CT		MBR 1550 CT				MBR 15150 CT	UNIT
Critical rate of rise of off-state voltage	dv/dt	10,000					V/µs		
Junction temperature	T_J	-55 to +150				°C			
Storage temperature	T _{STG}	Γ _{STG} -55 to +150				°C			

Notes:

1. $tp = 2.0\mu s$, 1.0KHz

THERMAL PERFORMANCE							
PARAMETER	SYMBOL	TYP	UNIT				
Junction-to-ambient thermal resistance	R _{OJA}	10	°C/W				
Junction-to-case thermal resistance	R _{eJC}	1.5	°C/W				

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBR1535CT MBR1545CT	I _F = 7.5A, T _J = 25°C		-	-	٧
	MBR1550CT MBR1560CT			-	0.75	٧
	MBR1590CT MBR15100CT			-	0.92	V
	MBR15150CT			-	1.05	V
	MBR1535CT MBR1545CT			-	0.84	V
	MBR1550CT MBR1560CT	I _F = 15A, T _J = 25°C	V _F	-	-	V
	MBR1590CT MBR15100CT			-	-	٧
Forward voltage per	MBR15150CT			-	-	V
Forward voltage per diode ⁽¹⁾	MBR1535CT MBR1545CT	I _F = 7.5A, T _J = 125°C		-	0.57	V
	MBR1550CT MBR1560CT			-	0.65	V
	MBR1590CT MBR15100CT			-	0.82	V
	MBR15150CT			-	0.92	V
	MBR1535CT MBR1545CT			-	0.72	V
	MBR1550CT MBR1560CT			-	-	٧
	MBR1590CT MBR15100CT			-	-	٧
	MBR15150CT			-	-	V



ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)									
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT			
Reverse current @ rated V _R per diode ⁽²⁾ M M M M M M M M M M M M M M M M M M	MBR1535CT MBR1545CT	T _J = 25°C	- I _R	-	500	μΑ			
	MBR1550CT MBR1560CT			-	300	μΑ			
	MBR1590CT MBR15100CT MBR15150CT			-	100	μΑ			
	MBR1535CT MBR1545CT	T _J = 125°C		-	10	mA			
	MBR1550CT MBR1560CT			-	7.5	mA			
	MBR1590CT MBR15100CT MBR15150CT			-	5	mA			

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION							
ORDERING CODE(1)(2)	PACKAGE	PACKING					
MBR15xCT	TO-220AB	50 / Tube					
MBR15xCTH	TO-220AB	50 / Tube					

Notes:

- 1. "x" defines voltage from 35V(MBR1535CT) to 150V(MBR15150CT)
- 2. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

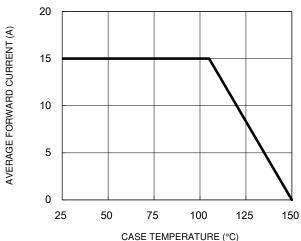


Fig.3 Typical Reverse Characteristics

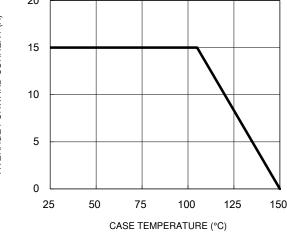


Fig.2 Typical Junction Capacitance

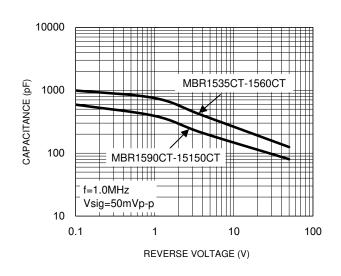
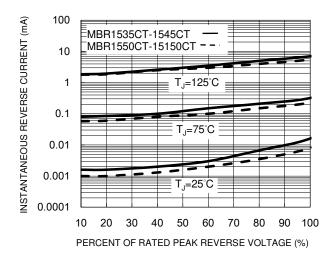


Fig.4 Typical Forward Characteristics



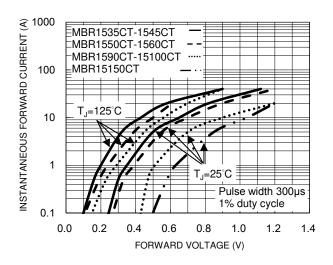
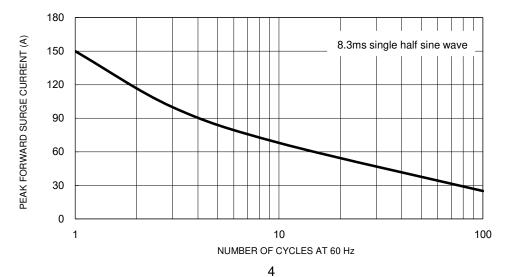


Fig.5 Maximum Non-Repetitive Forward Surge Current

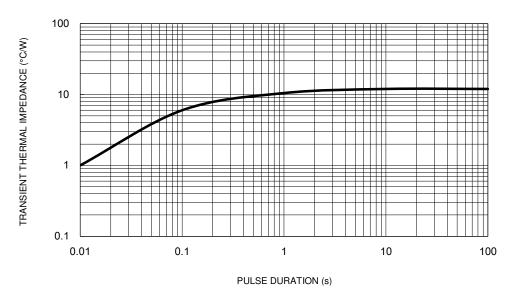


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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

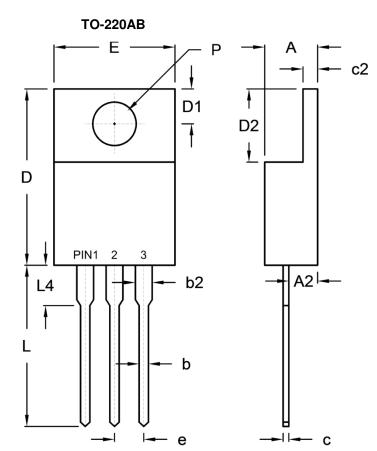
Fig.6 Typical Transient Thermal Impedance





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PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
Dilvi.	Min.	Max.	Min.	Max.	
Α	4.42	4.76	0.174	0.187	
A2	2.20	2.80	0.087	0.110	
b	0.68	0.94	0.027	0.037	
b2	1.14	1.77	0.045	0.070	
С	0.35	0.64	0.014	0.025	
c2	1.14	1.40	0.045	0.055	
D	14.60	16.00	0.575	0.630	
D1	2.62	3.44	0.103	0.135	
D2	5.84	6.86	0.230	0.270	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
L	13.19	14.79	0.519	0.582	
L4	2.80	4.20	0.110	0.165	
Р	3.54	4.00	0.139	0.157	

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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